



L Number	Hits	Search Text	DB	Time stamp
1	10835	semiconductor and (ldd or (lightly adj doped adj drain))	USPAT; US-PGPUB;	2002/10/06 09:00
	:		EPO; JPO; DERWENT;	
2	7181	(semiconductor and (ldd or (lightly adj doped adj drain))) and (gate adj	IBM_TDB USPAT; US-PGPUB;	2002/10/06 09:00
1		electrode)	EPO; JPO; DERWENT;	
3	535	{{semiconductor and {ldd or {lightly	IBM_TDB USPAT:	2002/10/06
ı	033	adj doped adj drain))) and (gate adj	US-PGPUB;	09:04
:		electrode)) and (taper\$3)	EPO; JPO; DERWENT;	
			IBM_TDB	